

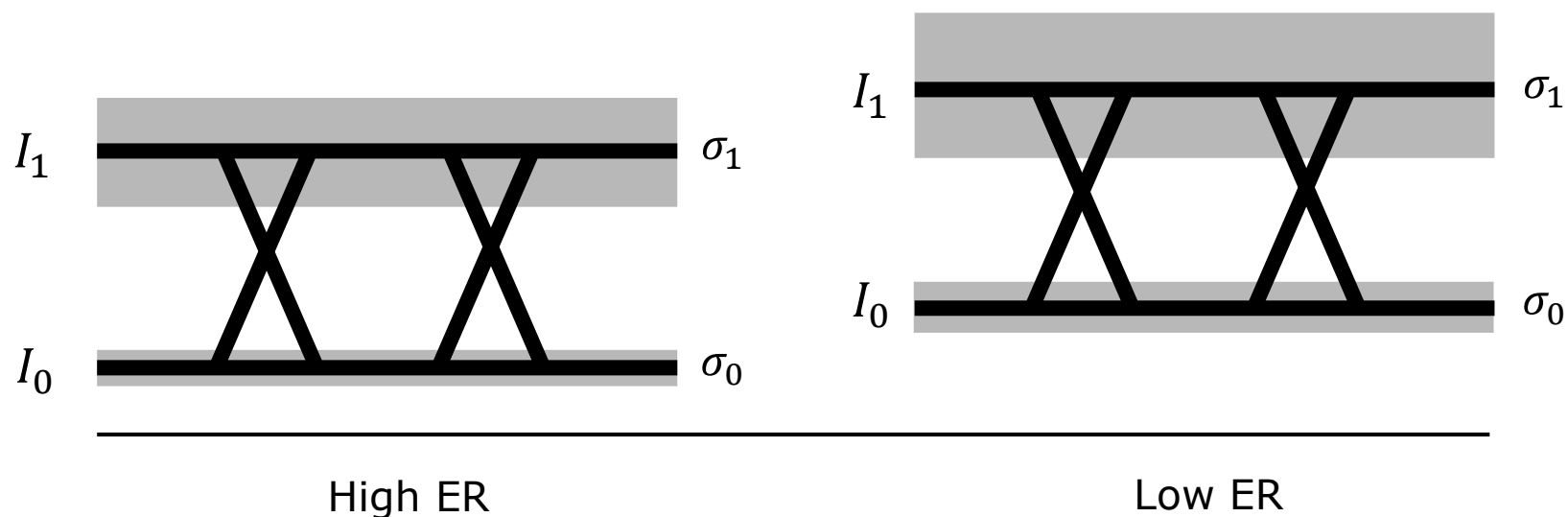
# ER Dependency of APD Receiver Sensitivity

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# Supporter

# Motivation

- OMA sensitivity of APD receiver shows ER dependency due to APD shot noise. In this presentation, I'll show calculated ER penalties.



$$I_1 = MRP_{OMA} \frac{ER}{ER-1} \quad (\text{A})$$

$$I_0 = MRP_{OMA} \frac{1}{ER-1} \quad (\text{A})$$

$R$  : O/E Responsivity (A/W)

$M$  : APD multiplication gain

$P_{OMA}$  : Received Optical Power in OMA (W)

$ER$  : Extinction Ratio

# APD Current Noise Calculation

$$\sigma_{APD} = \sqrt{2q(i + i_d)FM^2B} \quad (A)$$

$q$  : elementary charge (=1.602x10<sup>-19</sup> C)

$M$  : APD multiplication gain

$i$  : APD current (M=1) (A)

$i_d$  : APD dark current (M=1) (A)

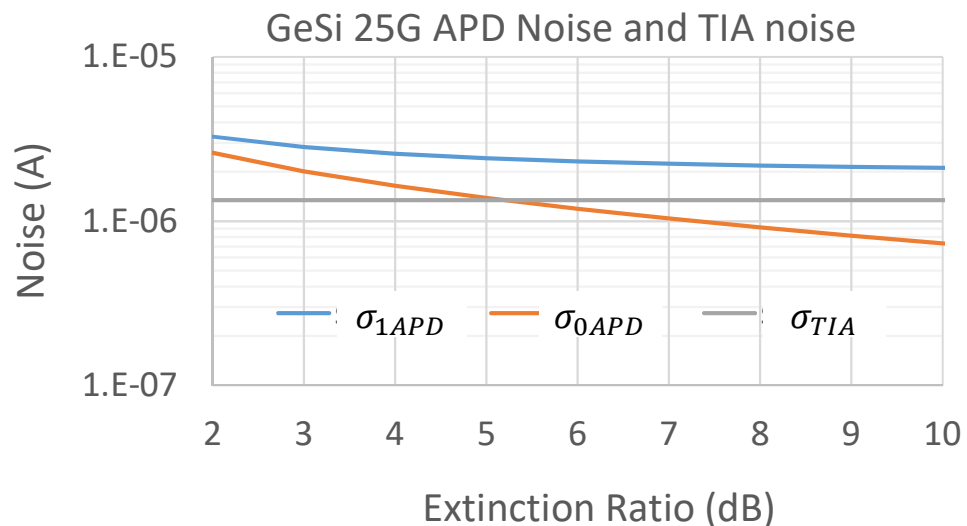
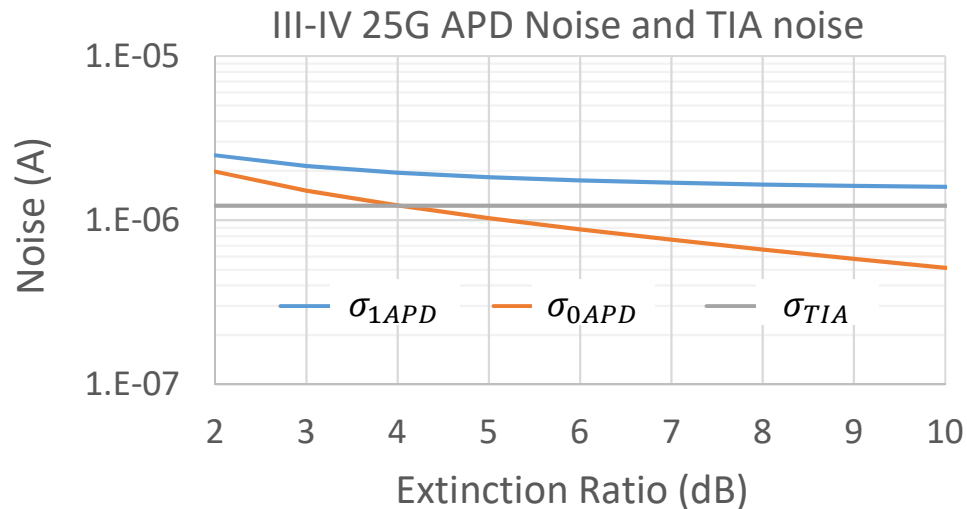
$B$  : receiver bandwidth (Hz)

$F$ : excess noise factor

$$F = kM + (2 - 1/M) (1 - k) \quad k : \text{ionization-coefficient ratio}$$

Reference: [http://www.ieee802.org/3/ca/public/meeting\\_archive/2016/09/pan\\_3ca\\_1\\_0916.pdf](http://www.ieee802.org/3/ca/public/meeting_archive/2016/09/pan_3ca_1_0916.pdf)

# ER Dependency of APD Noise



## Representative parameter values

Parameter	III-IV	GeSi	Unit
$P_{OMA}^{(1)}$	-24.83		dBm
$k$	0.45	0.13	
$i_d^{(2)}$	10	60	nA
$M^{(2)}$	7	10	
$R$	0.7		A/W
$B^{(2)}$	15	18	GHz
$\sigma_{TIA}^{(3)}$	1.22	1.34	uA

### Note

- (1) OLT sensitivity at BER=1e-2
- (2) GeSi APD has wider bandwidth with high M, but dark current is larger than III-IV.
- (3) Assumed TIA noise is constant over frequency for simplicity.

$$\sigma_{TIA} = 10 \text{ pA}/\sqrt{\text{Hz}} \times \sqrt{B} \quad (\text{A})$$

# ER Dependency of APD Noise

Total noise of APD and TIA is:

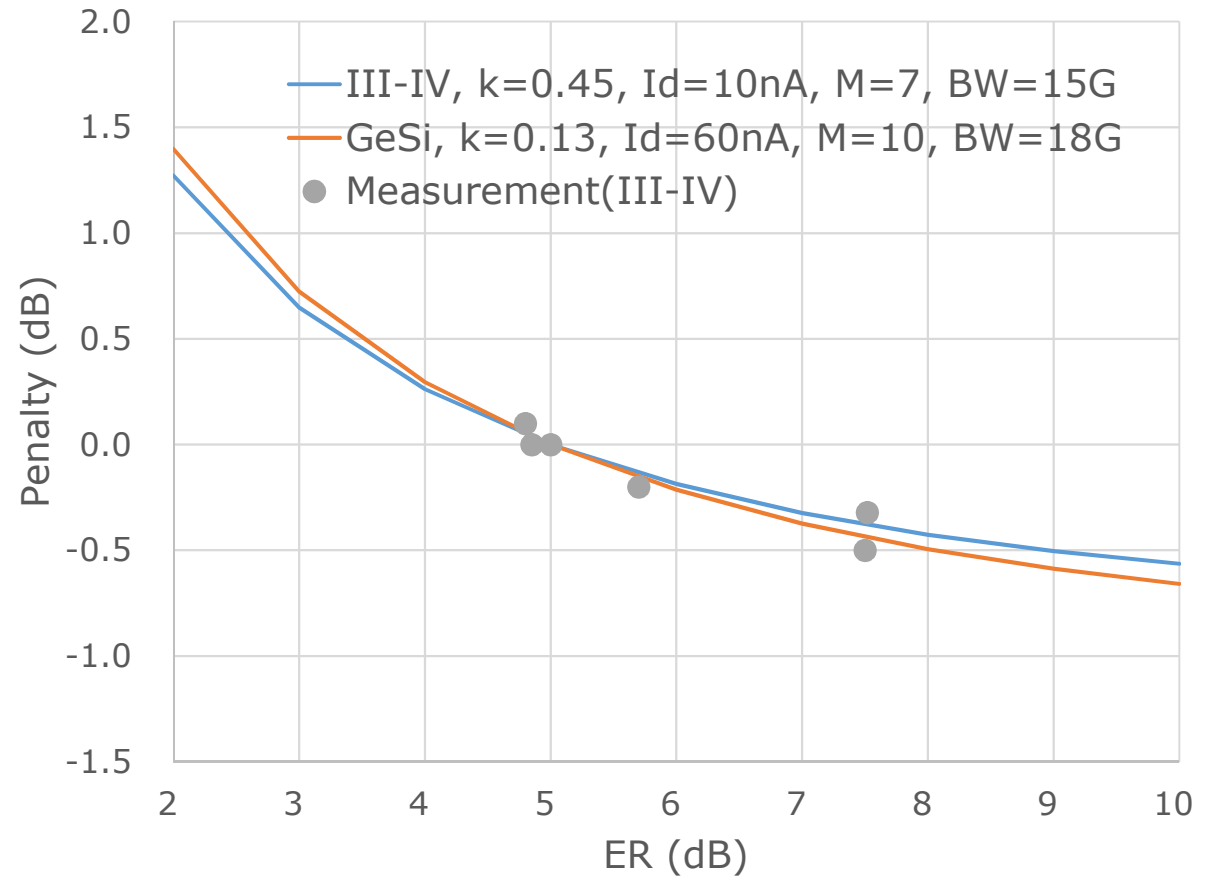
$$\sigma_1 = \sqrt{\sigma_{1APD}^2 + \sigma_{TIA}^2}$$

$$\sigma_0 = \sqrt{\sigma_{0APD}^2 + \sigma_{TIA}^2}$$

ER dependent penalty of OMA sensitivity is:

$$Penalty = 10 \log \left( \frac{Q(ER)}{Q(ER=5dB)} \right)$$

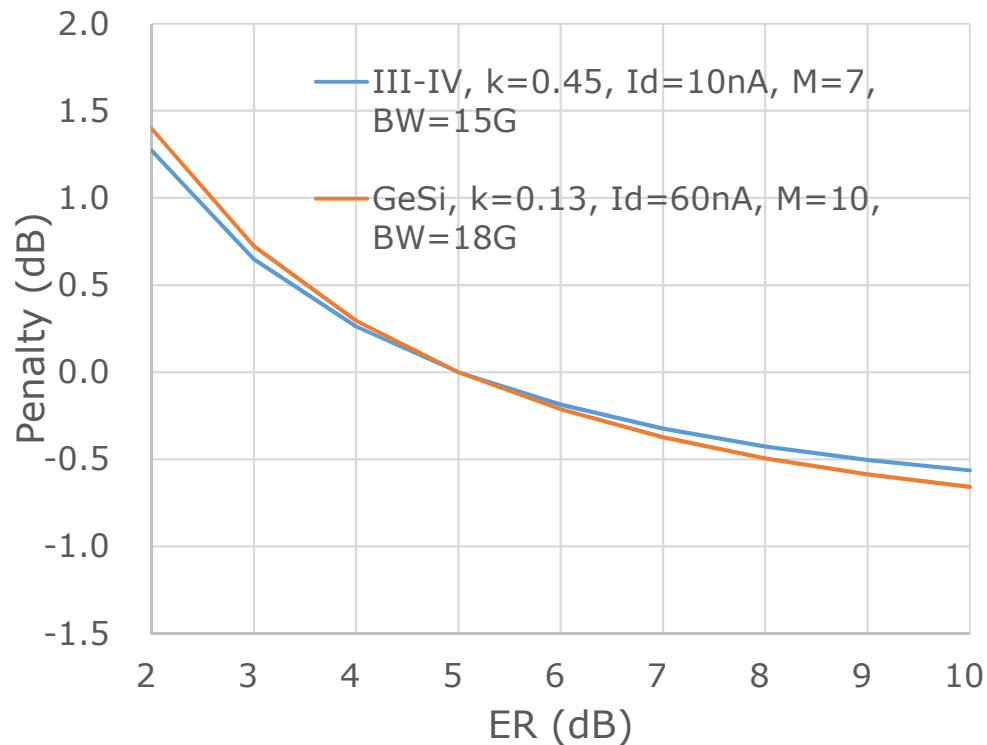
$$Q(ER) = \frac{I_1 - I_0}{\sigma_1 + \sigma_0}$$



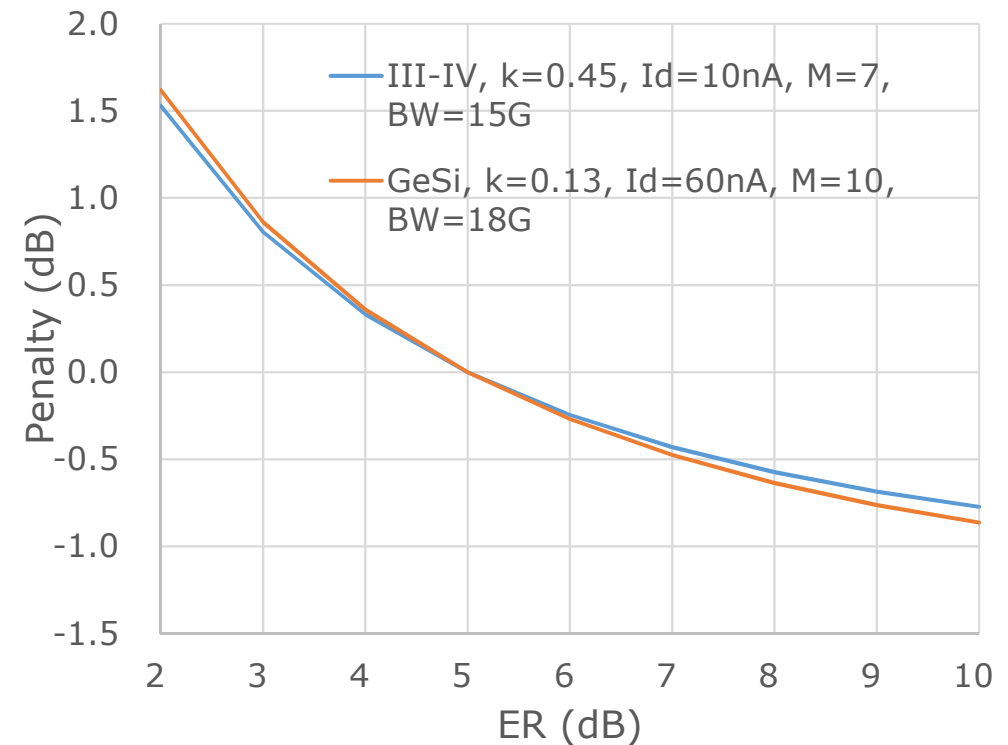
Measurement plots are from tanaka\_3ca\_1\_1116.pdf

# ER Dependency of APD Noise

The penalty has dependency on received power level.



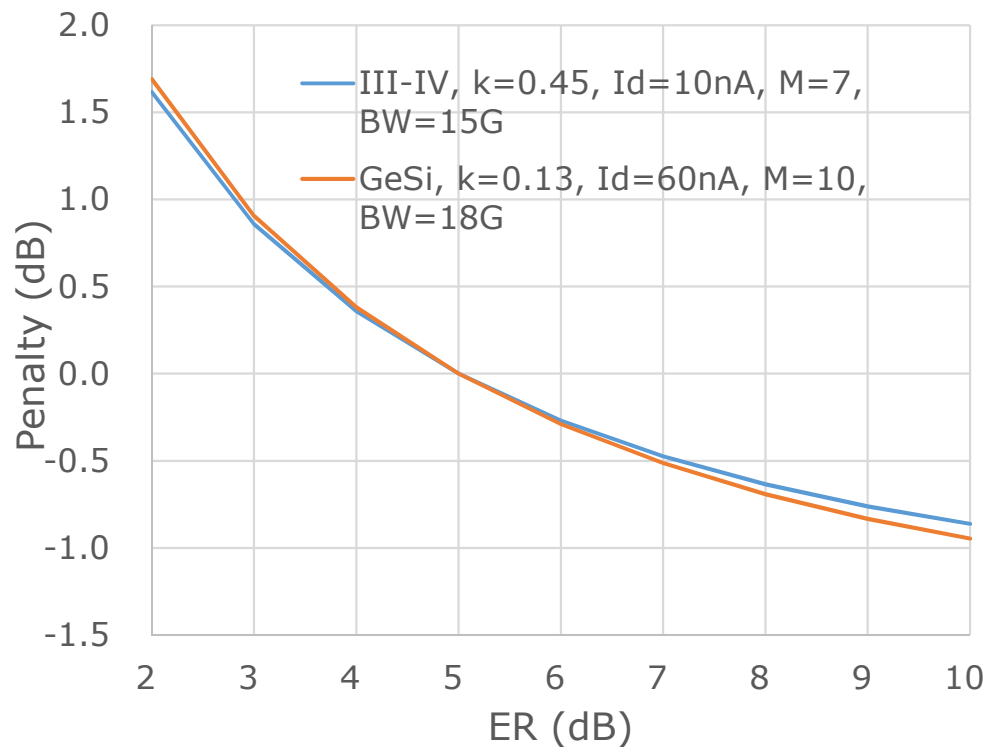
$P_{OMA} = -24.83$  dBm  
(25G OLT sensitivity @BER=1e-2)



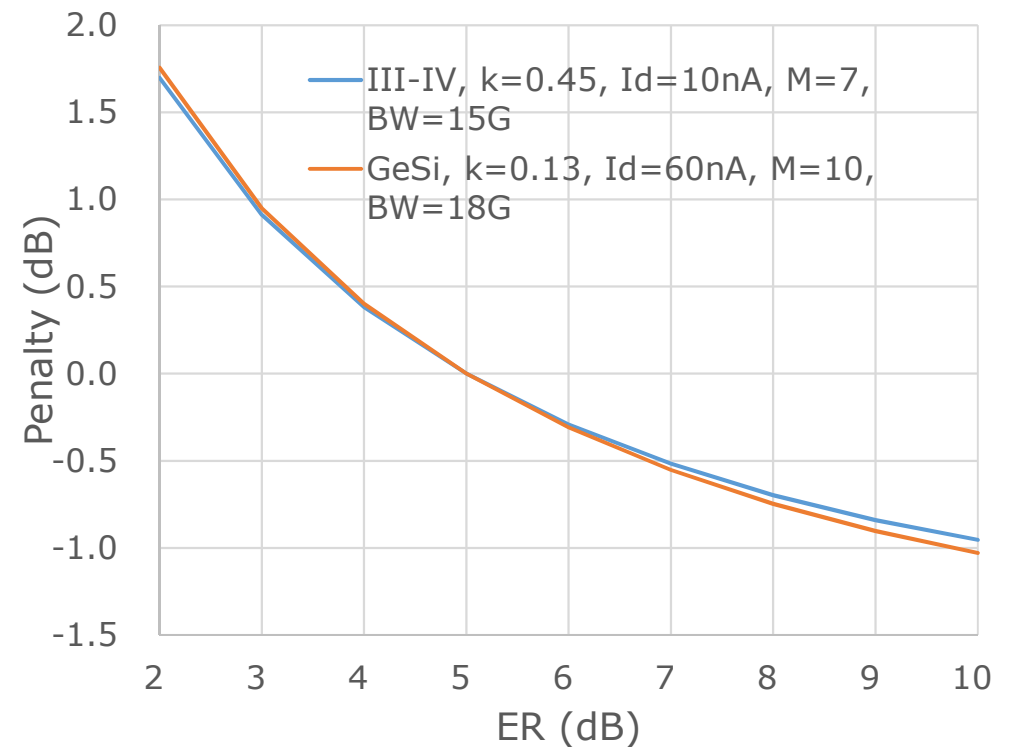
$P_{OMA} = -21.83$  dBm  
(25G OLT sensitivity + 3dB)

# ER Dependency of APD Noise

The penalty has dependency on received power level.



$P_{OMA} = -20.5 \text{ dBm}$   
(4WDM MSA 40km)



$P_{OMA} = -19.0 \text{ dBm}$   
(25GBASE-ER)



# Summary

- OMA sensitivity of APD receiver has ER dependency and showed calculated ER penalties for III-IV and GeSi APD.
- Need to consider the penalty to relax ER specification.